## Low tem perature ferrom agnetism in (Ga, Mn)N

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The magnetic properties of dilute magnetic sem iconductors (DMSs) are calculated from rstprinciples by m apping the ab initio results on a classical H eisenberg m odel. By using the K orringa-K ohn-R ostoker coherent potential approxim ation (KKR-CPA) method within the local density approximation, the electronic structure of (Ga, Mn)N and (Ga, Mn)As is calculated . E ective exchange coupling constants J<sub>ij</sub>'s are determ ined by embedding two M n impurities at sites i and j in the CPA medium and using the  $J_{ij}$  form ula of Liechtenstein et al. It is found that the range of the exchange interaction in (G a, M n)N, being dom inated by the double exchange m echanism, is very short ranged due to the exponential decay of the in purity wave function in the gap. On the other hand, in (Ga, Mn)As where p-d exchange mechanism dom inates, the interaction range is weaker but long ranged because the extended valence hole states mediate the ferrom agnetic interaction. Curie temperatures ( $T_c$ 's) of DMSs are calculated by using the mean eld approximation (MFA), the random phase approximation (RPA) and the, in principle exact, M onte Carlo method. It is found that the  $T_c$  values of (Ga, Mn)N are very low since, due to the short ranged interaction, percolation of the ferrom agnetic coupling is di cult to achieve for sm all concentrations. The MFA strongly overestim ates  $T_c$ . Even in (G a, M n)A s, where the exchange interaction is longer ranged, the percolation e ect is still in portant and the M FA overestim ates  $T_{\rm C}$  by about 50-100%.

D ilute m agnetic sem iconductors (DM Ss), such as (In, M n)As and (G a, M n)As discovered by M unekata et al. and Ohno et al., have been well investigated as hopeful m aterials for spintronics<sup>1</sup>. Curie tem peratures ( $T_{c}$  's) of these DM Ss are wellestablished<sup>1,2,3</sup> and som e prototypes of spintronics devices have been produced based on these DM Ss. The magnetism in these DM Ss are theoretically investigated and it is known that the ferrom agnetism in these system s as well as (G a, M n) Sb can be well described by Zener's p-d exchange interaction, due to the fact that the majority d-states lies energetically in the lower part of the valence band<sup>4</sup>. Dietlet al.<sup>5</sup> and M acD onald et al.6 successfully explained m any physical properties of (Ga, Mn)As based on the p-d exchange model, and rstprinciples calculations by Sato et al. showed that the concentration dependence of  $T_{\rm C}$  in (Ga, Mn)As was well understood by the p-d exchange interaction if a correction to the local density approxim ation (LDA) is simulated by the LDA + U m ethod with U =  $4 \text{ eV}^4$ .

W hile these p-d exchange systems, in which the dstates of M n impurities are practically localized, are well understood, there exist an even larger class of systems where the d-levels lie in the gap exhibiting impurity bands for su ciently large concentrations. To these im purity band system sbelong (G a, M n)N, (G a, C r)N, (G a, C r)As, (Zn, C r)Te, (Zn, C r)Se and m any others as shown by rst-principles calculations<sup>2</sup>. M ost of these systems are controversially discussed in the literature, and an unam biguous determ ination of the ferror agnetism has only been reported for (Zn, Cr)Te with a relatively high Cr concentration of 20% and a Curie temperature of 300 K<sup>8</sup>. In particular in this class of materials, (Ga, Mn)N has been frequently mentioned as the most promising high-T<sub>C</sub> DMS referring to the prediction of model calculations by D ietlet al.<sup>5</sup> and ab-initio results by Sato et al.9. M any groups have tried to fabricate ferrom agnetic (Ga, Mn)N, but the experim ental results are very controversial and confusing. A fter the st observation of the ferrom agnetism of (Ga, Mn)N<sup>10</sup>, many experiments followed, however reported  $T_{\rm C}$  's are scattered between 20 to 940 K<sup>10,11,12,13,14</sup>. M oreover, recently P loog et al. observed spin-glass behavior in 7% Mn-doped GaN and suggested that the ferrom agnetism observed in 14% M ndoped GaN originated from Mn-rich clusters<sup>15</sup>. Thus, the ferrom agnetism in (Ga, Mn)N is still an open question which we reconsider in this letter. Ab initio calculations by Akai<sup>16</sup> and others<sup>4,9,17,18,19,20</sup> show that the m agnetic properties of the above in purity band system s are dom inated by double exchange mechanism and that the ferrom agnetism is stabilized by the broadening of the impurity band. In the mean eld approximation (MFA) high T<sub>c</sub> values have been predicted (e.g., 350 K for (G a, Mn)N with 5% of Mn, 500 K for (Ga, Cr)N with 5% of Cr, 400 K for (Zn, Cr) Te with 5% of Cr and so on) and  $\overline{c}$ -dependence of  $T_c$  on concentration c has been the explained by band broadening<sup>4,17</sup>. Sim ilar high, though slightly sm aller, T<sub>C</sub> values have also been obtained in the random phase approximation (RPA).

In this paper, we will show that a general obstacle for ferrom agnetism exists in these dilute systems, in particular in (Ga, Mn)N. Due to the large band gap the wave function of the in purity state in the gap is well localized, leading to a strong, but short ranged exchange interaction, being dom inated by the nearest neighbors. Therefore, for low concentrations, the percolation of a ferrom agnetic cluster through the whole crystal cannot be achieved, so that a ferrom agnetic alignment of the impurity moments cannot occur. Thus a param agnetic or disordered, spin-glass like, state is observed, in particular for low concentrations.

The electronic structure of DMS is calculated based on the local density approximation (LDA) by using the Korringa-Kohn-Rostoker (KKR) method. In this paper we focus on (Ga, Mn)N and (Ga, Mn)As as typical examples for the double exchange and the p-d exchange system s, respectively. In these system s, M n impurities distribute random ly at G a sites in the host sem iconductorbeing described as (G a<sub>1 c</sub> , M n<sub>c</sub>)X , where c is the M n concentration and X refers to N or As. To describe the substitutional disorder, we use the coherent potential approximation (CPA). In this fram ework, all M n impurities are equivalent and consequently we suppose a ferrom agnetic alloy. It has already been shown that the magnetic properties of m etallic ferrom agnetic alloys are well described within the CPA<sup>21</sup>. W hile the CPA describes the electronic structure in the mean eld approximation, we go beyond this approximation and explicitly calculate the exchange interaction J<sub>ii</sub> between two im purities at sites i and i, which are embedded in the ferrom agnetic CPA  $\, m \, edium$  . For the evaluation of  $J_{\, i j} \, w \, e \, u \, s e$  the frozen potential approxim ation<sup>22</sup> and apply a form ula by Liechtenstein et al<sup>23</sup>. A coording to this form ula, the total energy change due to in nitesim al rotations of the two magnetic moments at site i and j is calculated using the magnetic force theorem, and the total energy change is mapped on the (classical) Heisenberg model  $i \neq j J_{ij} e_i e_j$ , where  $e_i$  is a unit vector parallel to H = the magnetic moment at site i, thus resulting in the effective exchange coupling constant J<sub>ij</sub>. This approach is already employed to estimate magnetic interactions in DM Ss by Turek et al.<sup>24</sup> and Bouzerar et al.<sup>25</sup>. For the present KKR-CPA calculations, we use the package MACHIKANEYAMA2000 coded by  $A \text{ ka}^{26}$ . We assume mu n-tin potentials and use the experimental lattice constants of the host sem iconductors $^{27}$ . It has already been shown that the lattice relaxations in (Ga, Mn)N and (Ga, Mn)As are very small<sup>20,28,29</sup>. Zincblende structures are assumed both for GaN and GaAs. In reality, GaN has W urtzite structure. However, results for both structures are practically identical, because splitting of in purity bands due to symmetry low ering is small<sup>20</sup> and disorder induced band width always overcom es the splitting. The angular momenta are cut o at l = 2 in each mu n-tin sphere. All calculations are performed for the neutral charge state of Mn, so that doping e ects are not included.

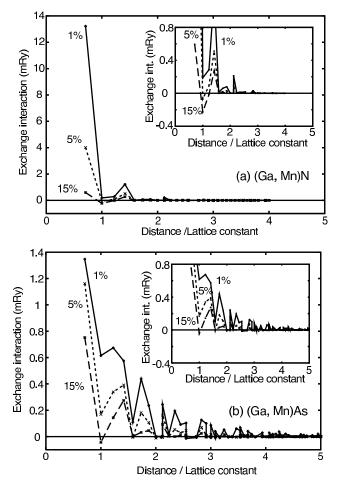


FIG.1: Calculated exchange interaction  $J_{ij}$  in (a) (Ga, Mn)N and (b) (Ga, Mn)As as a function of distance.

Fig. 1 shows the calculated exchange interactions J<sub>ii</sub> in (Ga, Mn)N and (Ga, Mn)As. As shown in the g.1-(a), in (G a, M n)N the interaction strength is strong, but the interaction range is short, so that the exchange coupling between nearest neighbors dom inates. For exam ple, nearest neighbor interaction J<sub>01</sub> in 1% Mn-doped GaN is about 13.5 m Ry, while the other interactions are alm ost 2 orders of magnitude smaller than  $J_{01}$  except for  $J_{04}$ . Therefore, in this case the very large mean eld value of  $T_c$  is mostly determined by  $J_{01}$ . For higher concentrations, J<sub>01</sub> is suppressed and the interaction between next nearest neighbors becom es negative, resulting a complicated structure in the distance dependence of the exchange interaction. Concerning to the mechanism of the ferrom agnetism, it has already been pointed out that the double exchange mechanism dom inates in (Ga, M n)N where pronounced impurity bands appear in the  $qap^{4,7,9,17}$ . It is intuitively understood that the exchange interaction in (Ga, Mn)N becomes short ranged due to the exponential decay of the impurity wave function in the gap. In contrast to (Ga, Mn)N, the exchange interaction has long tails in (Ga, Mn)As in particular for low concentrations as shown in g. 1-(b). The qualitative

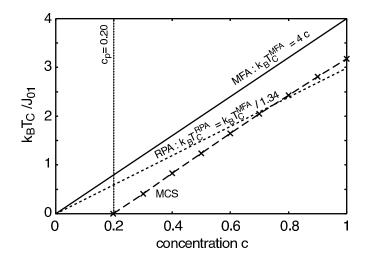


FIG.2: Curie temperatures of nearest neighbor H eisenberg m odel in fcc structure.  $T_{\rm C}$  's are calculated by the m ean eld approximation (solid line), the random phase approximation (dotted line) and M onte Carlo simulation (crosses). The per-colation threshold is 0.20 for the fcc structure.

di erence in the interaction range between (G a, M n)N and (G a, M n)As is apparent from the gure. In (G a, M n)As the p-d exchange interaction becomes in portant as shown in ref.<sup>4</sup>. Since the extended hole state mediates the ferrom agnetic interaction<sup>5</sup>, the interaction range is long ranged in p-d exchange systems essentially. A ctually the interaction extends farther than 3 lattice constants (20th shell). For higher concentrations, due to the screening of the pair interaction by the other in purities, interaction range becomes slightly shorter.

As is well known the LDA predicts the position of localized d-levels at too high energy. How ever, according to recent calculations by Shick et  $al^{30}$ , the LDA+U calculations only slightly a ect the impurity bands at the Fermilevelin (Ga, Mn)N due to the extended nature of the anti-bonding to states of the impurity bands. Therefore, the LDA provides a fairly good description of the magnetic properties of (Ga, Mn)N. Even if the nearest neighbor interactions are changed in the LDA+U calculations, this will not a ect much the Curie tem peratures for low concentrations, because only the longer ranged interactions are relevant due to the percolation e ects. On the other hand, as we have already shown in ref.<sup>4</sup>, the LDA+U calculations with U=4eV yield a di erent description of the magnetism in (Ga, Mn)As. This e ect could change the calculated T<sub>C</sub> values slightly, how ever, the exchange interaction in (Ga, Mn)As still remains long ranged and the basic argum ent of the follow ing discussion is not a ected.

It is well known that the Curie temperature in the mean eld approximation  $T_{\rm C}^{\rm M\,FA}$  is calculated as  $k_{\rm B}\,T_{\rm C}^{\rm M\,FA}=\frac{2}{3}\,c_{\rm i6\,0}\,J_{0\,i}$ , where  $k_{\rm B}$  is Boltzm ann constant. As shown in this equation, evaluation of  $T_{\rm C}^{\rm M\,FA}$  does not require any inform ation on the interaction range, because only the sum of the coupling constants appears in the

equation. This simpli cation leads to signi cant errors in the calculated T<sub>c</sub> of a dilute system with low concentrations. This fact is easily understood by sim ple consideration and is known as the percolation problem <sup>31</sup>. Let us suppose a Heisenberg model with a ferrom agnetic exchange interaction only between nearest neighbors (nearest neighbor H eisenberg m odel), and consider w hat happens when the system is diluted with non-magnetic sites. W hen the concentration of magnetic sites is 100%, we have a perfect ferrom agnetic network. Due to the dilution, the network is weakened, and for a concentration below a percolation threshold the ferrom agnetism cannot spread all over the system leading to param agnetic state since due to m issing longer ranged interactions the m om ents can no longer align. O bviously this e ect is not counted in the mean eld equation for  $T_c$ , because the dilution e ect is included only as a concentration factor c in the equation. In case of the nearest neighbor Heisenberg model, the percolation thereshold co for fcc structure is 20% <sup>31</sup>. In real cases the exchange interaction could reach beyond the nearest neighbors and the percolation threshold might be lower. However, in this paper we are interested in the concentration range well below the nearest neighbor threshold  $c_{\!p}\,.$  Therefore the exact  $T_C$  values could be much lower than the mean eld values, in particular for the double exchange system s like (Ga, Mn)N where the exchange interaction is very short ranged (g.1-(a)).

In order to take the percolation e ect into account, we perform Monte Carlo simulations (MCS) for the e ective classical H eisenberg m odel. The therm all average of m agnetization M and its powers are calculated by m eans of the M etropolis algorithm <sup>32</sup>. Due to the nite size of super cells used in the simulation, it is di cult to determ ine  $T_C$  from the temperature dependence of hM (T)i. In particular, when considering dilute systems, nite size e ects and appropriate nite size scaling are of particular in portance for a correct and e cient evaluation of  $T_{C}$ by M onte Carlo simulations. To avoid this di culty, we use the cum ulant crossing m ethod proposed by B inder<sup>32</sup>. Thism ethod uses the nite size scaling in the fourth order cum ulant U<sub>4</sub> which is de ned as U<sub>4</sub> = 1 hM  ${}^{4}$  i= (3hM  ${}^{2}$  i ${}^{2}$ ). U<sub>4</sub> is calculated for various cell sizes and plotted as a function of tem perature. If the cell size is larger than the correlation length, it can be shown that the  $U_4$  (T) curves for di erent sizes cross each other at three characteristic tem peratures. Two of them are T = 0 and T = 1 , and the other is  $T = T_c$  . We use 3 cell sizes (6 6 6;10 10 10 and 14 14 14 conventional fcc cells) to carry out the cum ulant crossing m ethod for  $T_{\rm C}$ calculations. For each tem perature, we perform 240000 M onte C arlo steps per site using every 20-th step for averaging.

First, as a pedagogical example we show the calculated  $T_C$  for the dilute fcc nearest neighbor Heisenberg model as calculated by MFA, RPA and MCS in g.2. For MCSs for dilute systems, we take 20 di erent random con gurations of magnetic sites for the ensemble average. As

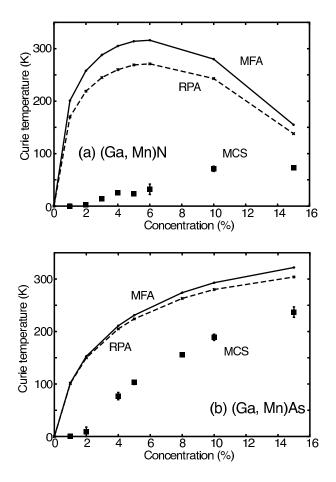


FIG.3: Curie temperatures of (a) (Ga, Mn)N and (b) (Ga, Mn)As calculated by the MFA (solid lines), the RPA (dotted lines) and the MCS (lled squares). For the MCS, the exchange interactions up to 15th shellare taken into account.

shown in g.2, it is found that both MFA and RPA give reasonable estimations of  $T_{C}$  for c = 1, with the RPA being closer to exact M C S result. It has been analytically shown that for this model MFA gives upper lim it of  $T_{C}$ and RPA gives lower lim it<sup>33</sup>. However, for c 0:7, MCS results are below RPA values and in particular below the percolation thereshold ( $c_p = 0.20$ ) the Curie temperature vanishes:  $T_c = 0$ . Thus the serious de ciency of both MFA and RPA in the dilute concentration range is evident.

Next, we show the calculated  $T_C$  values of (G a, M n)N (g. 3-(a)) and (Ga, Mn)As (g. 3-(b)) as obtained by the MCS from the J<sub>ij</sub> values in g.1. Thirty con gurations of M n atom s are considered for averaging and J<sub>ii</sub>-interactions up to 15 shells are included; on the other hand, for the M FA and the R PA estim ations interactions are included up to 72 shells. As shown in g. 3-(a), very small T<sub>C</sub> values are predicted for low concentrations in

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(Ga, Mn)N.MFA and RPA values are alm ost 2 orders of m agnitude too large. Thus we nd that the magnetism is strongly suppressed due to the missing percolation of the strong nearest neighbor interactions. Only the weak, longer ranged interactions satisfy the percolation requirement, leading to smallbut nite Curie tem peratures for 5,10, and 15% of Mn. As shown in g.3-(b), due to the longer ranged interaction in (G a, M n)As, the reductions from the MFA are not very large, but still signi cant. Naturally these changes are larger for smaller concentrations. The  $T_C$  values of 103 K obtained for 5% M n is in good agreem ent with the experim ental values of 118 K reported by Edm onds et al.<sup>2</sup>. This value refers to m easurements in thin Im swhich are free of Mn-interstitials representing double donors. Including interactions beyond the 15th shell, MCS could give slightly higher  $T_{C}$ values for low concentrations where the interactions do not converge within the 15th neighbors. At very high concentrations we expect our results to merge with the MFA and RPA values.

In this Letter, we have shown by ab-initio calculations that (Ga, Mn)N shows no high-tem perature ferrom agnetism for low M n concentrations. The strong ferrom agnetic interaction of M n nearest neighbor pairs does not become e ective below the nearest neighbor percolation lim it. The weak longer ranged interaction leads to a ferrom agnetic phase with very low T<sub>C</sub> of several tens K elvin. Therefore the experim entally observed very high T<sub>C</sub> values do not refer to a hom ogeneous ferrom agnetic phase, but have to be attributed to sm all ferrom agnetic M nN clusters and segregated M nN phases. Our results are of relevance for all DMS systems with impurity bands in the gap. To obtain higher Curie tem peratures one needs longer ranged interactions and/or higher concentrations. The latter requirem ent naturally points to II-V I sem iconductors, having a large solubility for transition m etal atom s. The observation of a  $T_{\rm C}\,$  value of 300 K for (Zn, Cr)Te with 20% Cr<sup>8</sup> is in line with these argum ents. Sim ilar results as presented above have been recently reported by a Swedish-Czech collaboration<sup>34</sup>

## A cknow ledgm ents

This research was partially supported by JST-ACT, NEDO-nanotech, a Grant-in-Aid for Scienti c Research on Priority Areas A and B, SANKEN-COE and 21st Century COE from the M inistry of Education, Culture, Sports, Science and Technology. This work was also partially supported by the RT Network Computational Magnetoelectronics (Contract RTN 1-1999-00145) of the European Commission.

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